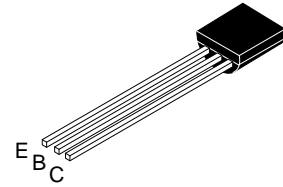


# PNP General-Purpose Transistor

## PN2907



TO-92 3 4.825x4.76  
CASE 135AN

### Description

This device is designed for use with general-purpose amplifiers and switches requiring collector currents to 500 mA.

These devices are Pb-Free, Halogen Free/BFR Free, Beryllium Free and are RoHS compliant.

### ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C unless otherwise noted) (Note 1, 2)

Symbol	Parameter	Value	Unit
V <sub>CEO</sub>	Collector-Emitter Voltage	-40	V
V <sub>CBO</sub>	Collector-Base Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5.0	V
I <sub>C</sub>	Collector Current - Continuous	-800	mA
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

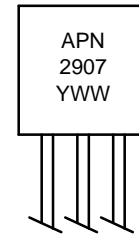
- These ratings are based on a maximum junction temperature of 150°C.
- These are steady-state limits. **onsemi** should be consulted on applications involving pulsed or low-duty cycle operations.

### THERMAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Max (Note 3)	Unit
P <sub>D</sub>	Total Device Dissipation	625	mW
	Derate Above 25°C	5.0	mW/°C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	83.3	°C/W
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	200	°C/W

- PCB size: FR-4 76 x 114 x 1.57 mm<sup>3</sup> (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

### MARKING DIAGRAM



PN2907 = Specific Device Code  
A = Assembly Site  
Y = Year of Production  
WW = Work Week Number

### ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

# PN2907

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Max	Unit
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### OFF CHARACTERISTICS

V <sub>(BR)CEO</sub>	Collector–Emitter Breakdown Voltage (Note 4)	I <sub>C</sub> = –10 mA, I <sub>B</sub> = 0	–40	–	V
V <sub>(BR)CBO</sub>	Collector–Base Breakdown Voltage	I <sub>C</sub> = –10 μA, I <sub>E</sub> = 0	–60	–	V
V <sub>(BR)EBO</sub>	Emitter–Base Breakdown Voltage	I <sub>E</sub> = –10 μA, I <sub>C</sub> = 0	–5.0	–	V
I <sub>CEX</sub>	Collector Cut–Off Current	V <sub>CE</sub> = –30 V, V <sub>EB</sub> = –0.5 V	–	–50	nA
I <sub>BL</sub>	Base Cut–Off Current	V <sub>CE</sub> = –30 V, V <sub>EB</sub> = –0.5 V	–	–50	nA
I <sub>CBO</sub>	Collector Cut–Off Current	V <sub>CB</sub> = –50 V, I <sub>E</sub> = 0	–	–20	nA
		V <sub>CB</sub> = –50 V, I <sub>E</sub> = 0, T <sub>A</sub> = 150°C	–	–20	μA

### ON CHARACTERISTICS (Note 4)

h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> = –10 V, I <sub>C</sub> = –0.1 mA	35	–	
		V <sub>CE</sub> = –10 V, I <sub>C</sub> = –1.0 mA	50	–	
		V <sub>CE</sub> = –10 V, I <sub>C</sub> = –10 mA	70	–	
		V <sub>CE</sub> = –10 V, I <sub>C</sub> = –150 mA	100	300	
		V <sub>CE</sub> = –10 V, I <sub>C</sub> = –500 mA	30	–	
V <sub>CE(sat)</sub>	Collector–Emitter Saturation Voltage	I <sub>C</sub> = –150 mA, I <sub>B</sub> = –15 mA	–	–0.4	V
		I <sub>C</sub> = –500 mA, I <sub>B</sub> = –50 mA	–	–1.6	
V <sub>BE(sat)</sub>	Base–Emitter Saturation Voltage	I <sub>C</sub> = –150 mA, I <sub>B</sub> = –15 mA	–	–1.3	V
		I <sub>C</sub> = –500 mA, I <sub>B</sub> = –50 mA	–	–2.6	

### SMALL SIGNAL CHARACTERISTICS

C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> = –10 V, f = 1.0 MHz	–	8	pF
C <sub>ib</sub>	Input Capacitance	V <sub>EB</sub> = –2.0 V, f = 1.0 MHz	–	30	pF
h <sub>fe</sub>	Small–Signal Current Gain	I <sub>C</sub> = –50 mA, V <sub>CE</sub> = –20 V, f = 100 MHz	2	–	

### SWITCHING CHARACTERISTICS

t <sub>on</sub>	Turn–On Time	V <sub>CC</sub> = –30 V, I <sub>C</sub> = –150 mA, I <sub>B1</sub> = –15 mA	–	45	ns
t <sub>d</sub>	Delay Time		–	10	ns
t <sub>r</sub>	Rise Time		–	40	ns
t <sub>off</sub>	Turn–Off Time	V <sub>CC</sub> = –6.0 V, I <sub>C</sub> = –150 mA, I <sub>B1</sub> = I <sub>B2</sub> = –15 mA	–	100	ns
t <sub>s</sub>	Storage Time		–	80	ns
t <sub>f</sub>	Fall Time		–	30	ns

4. Pulse test: pulse width ≤ 300 μs, duty cycle ≤ 2.0%.

### ORDERING INFORMATION

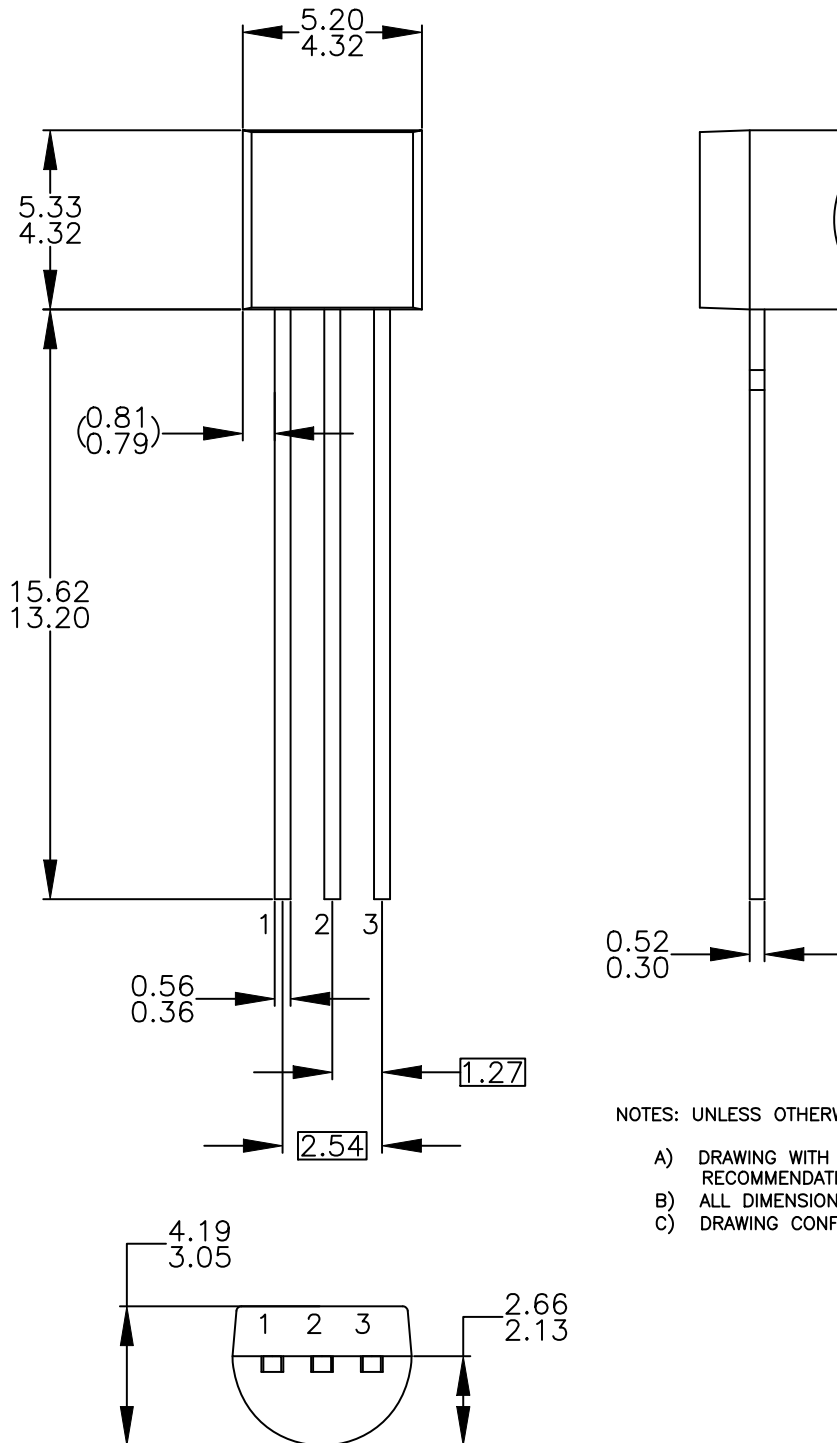
Part Number	Top Mark	Package	Shipping
PN2907BU	PN2907	TO–92 3 4.825x4.76 (Pb–Free)	10000 Units / Bulk

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**MECHANICAL CASE OUTLINE**  
**PACKAGE DIMENSIONS**

TO-92 3 4.825x4.76  
CASE 135AN  
ISSUE O

DATE 31 JUL 2016



NOTES: UNLESS OTHERWISE SPECIFIED

- A) DRAWING WITH REFERENCE TO JEDEC TO-92 RECOMMENDATIONS.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-2009.

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<b>DESCRIPTION:</b>	<b>TO-92 3 4.825X4.76</b>	<b>PAGE 1 OF 1</b>

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